

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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# 2SA1667/1668

Silicon PNP Epitaxial Planar Transistor (Complement to type 2SC4381/4382)

Application: TV Vertical Output, Audio Output Driver and General Purpose

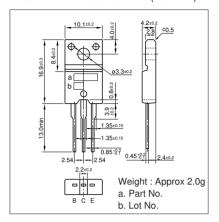
(Ta=25°C)

## ■Absolute maximum ratings (Ta=25°C) ■Electrical Characteristics

Symbol	Ra	Unit	
	2SA1667	2SA1667 2SA1668	
Vсво	-150	-200	٧
VCEO	-150	-150 -200	
VEBO	1	٧	
Ic	<b>–</b> 2		Α
Ів	<b>–1</b>		Α
Pc	25(Tc=25°C)		W
Tj	150		°C
Tstq	-55 to +150		°C

				,	,
Symbol	Conditions		Ra		
Syllibol			2SA1667	2SA1668	Unit
Ісво			-10max	-10max	μΑ
ТСВО		Vcb=	-150	-200	V
<b>I</b> EBO	VEB=-6V		-10max		μΑ
$V_{(BR)CEO}$	Ic=-25mA		-150min	–200min	V
hfe	Vce=-10V, Ic=-0.7A		60min		
Vce(sat)	Ic=-0.7A, IB=-0.07A		-1.0max		V
fτ	Vce=-12V, IE=0.2A		20typ		MHz
Сов	VcB=-10V, f=1MHz		60typ		pF

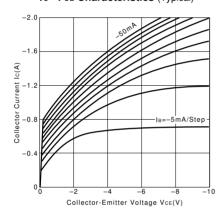
## External Dimensions FM20 (TO220F)



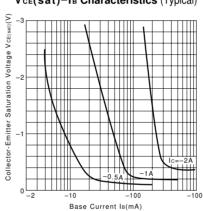
### ■Typical Switching Characteristics (Common Emitter)

Vcc	RL	Ic	V <sub>BB1</sub> (V)	VBB2	I <sub>B1</sub>	I <sub>B2</sub>	ton	tstg	tf
(V)	(Ω)	(A)		(V)	(mA)	(mA)	(µs)	(μs)	(μs)
-20	20	-1	-10	5	-100	100	0.4typ	1.5typ	0.5typ

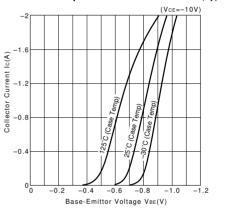
## Ic-VcE Characteristics (Typical)



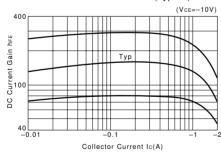
VcE(sat)-IB Characteristics (Typical)



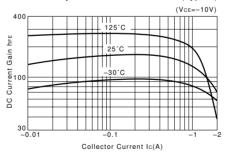
Ic-VBE Temperature Characteristics (Typical)



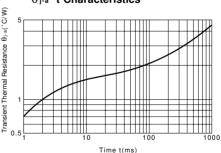
hfe-Ic Characteristics (Typical)



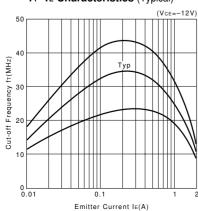
hfe-Ic Temperature Characteristics (Typical)



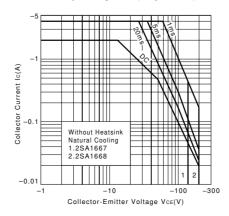
θ<sub>j-a</sub>-t Characteristics



fT-IE Characteristics (Typical)



Safe Operating Area (Single Pulse)



Pc-Ta Derating

